

PQMH13 NPN/NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω 4 November 2015

Product data sheet

1. **General description**

NPN/NPN Resistor-Equipped Transistors (RET) in a leadless ultra small DFN1010B-6 (SOT1216) Surface-Mounted Device (SMD) plastic package.

NPN/PNP complement: PQMD13.

Features and benefits 2.

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Low package height of 0.37 mm
- Reduces component count •
- Reduces pick and place costs
- AEC-Q101 qualified

3. Applications

- Low current peripheral driver
- Control of IC inputs
- Replaces general-purpose transistors in digital applications
- Mobile applications

Quick reference data 4.

Table 1. Quie	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
V _{CEO}	collector-emitter voltage	open base		-	-	50	V
I _O	output current			-	-	100	mA
Per transistor							-
R1	bias resistor 1	T _{amb} = 25 °C	[1]	3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		[1]	8	10	12	

[1] See section "Test information" for resistor calculation and test conditions.





5. Pinning information

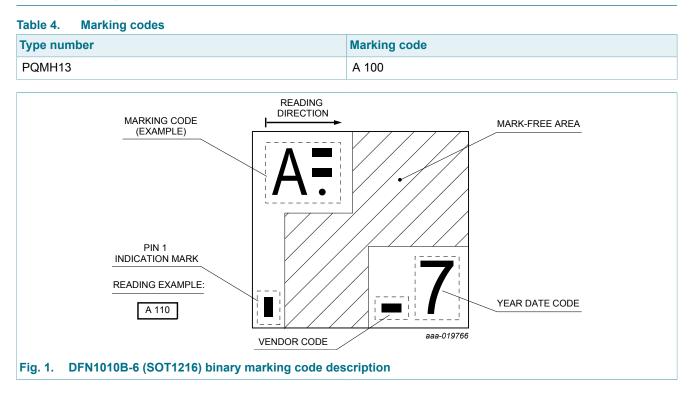
Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	11	input (base) TR1		
3	O2	output (collector) TR2	2 5	
4	GND2	GND (emitter) TR2		
5	12	input (base) TR2		
6	O1	output (collector) TR1	Transparent top view	
7	O1	output (collector) TR1	DFN1010B-6 (SOT1216)	GND1 I1 O2 aaa-019894
8	O2	output (collector) TR2		

6. Ordering information

Table 3. Ordering information						
Type number	Package	'ackage				
	Name	Description	Version			
PQMH13	DFN1010B-6	DFN1010B-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1216			

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7. Marking



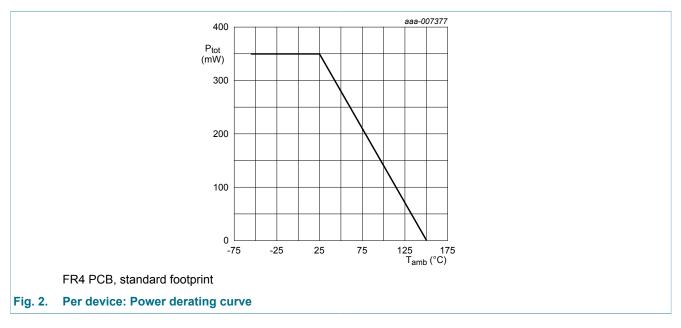
8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
Per transis	tor					
V _{CBO}	collector-base voltage	open emitter		-	50	V
V _{CEO}	collector-emitter voltage	open base		-	50	V
V _{EBO}	emitter-base voltage	open collector		-	5	V
VI	input voltage	positive		-	30	V
		negative		-	-5	V
I _O	output current			-	100	mA
I _{CM}	peak collector current			-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	230	mW
Per device						
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	350	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

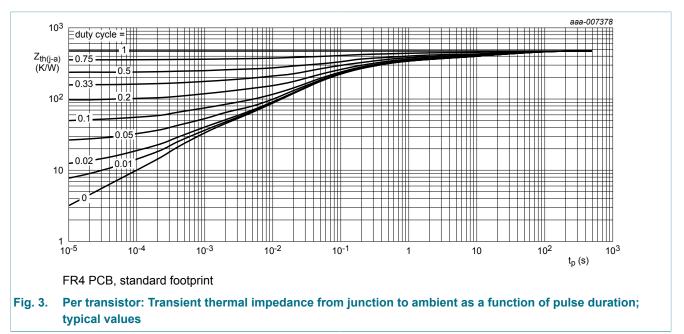


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9. Thermal characteristics

Table 6. The	rmal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
Per transistor							
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	543	K/W
Per device			·				
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	357	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



10. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
Per transis	tor						
I _{CBO}	collector-base cut-off current (emitter open)	V_{CB} = 50 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
I _{CEO}	collector-emitter cut-off	V_{CE} = 30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	1	μA
	current (base open)	V_{CE} = 30 V; I _B = 0 A; T _{amb} = 150 °C		-	-	5	μA
I _{EBO}	emitter-base cut-off current (collector open)	V_{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	170	μA
h _{FE}	DC current gain	V_{CE} = 5 V; I _C = 10 mA; T _{amb} = 25 °C		100	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_{C} = 5 mA; I_{B} = 0.25 mA; T_{amb} = 25 °C		-	-	100	mV
V _{I(off)}	off-state input voltage	V_{CE} = 5 V; I_{C} = 100 µA; T_{amb} = 25 °C		-	0.6	0.5	V
V _{I(on)}	on-state input voltage	V_{CE} = 0.3 V; I _C = 5 mA; T _{amb} = 25 °C		1.3	0.9	-	V
R1	bias resistor 1	T _{amb} = 25 °C	[1]	3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		[1]	8	10	12	
C _C	collector capacitance	V_{CB} = 10 V; I _E = 0 A; f = 1 MHz; T _{amb} = 25 °C		-	-	2.5	pF
f _T	transition frequency	V _{CE} = 5 V; I _C = 10 mA; f = 100 MHz; T _{amb} = 25 °C	[2]	-	230	-	MHz

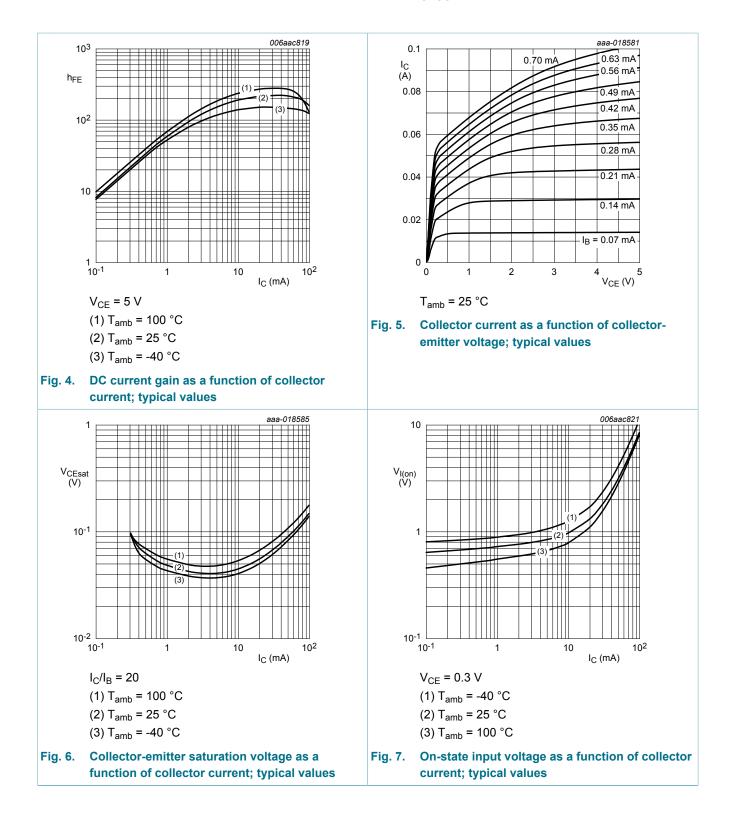
[1] See section "Test information" for resistor calculation and test conditions.

[2] Characteristics of built-in transistor

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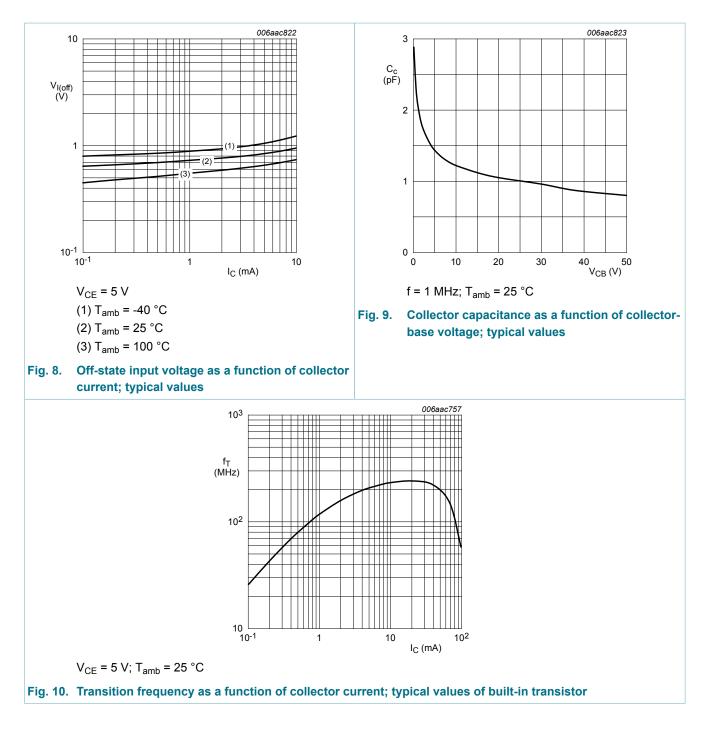
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11. Test information

11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

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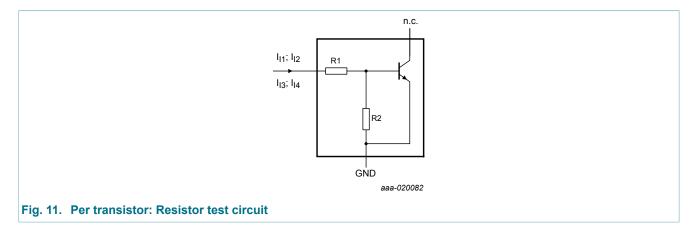
11.2 Resistor calculation

• Calculation of bias resistor 1 (R1)

$$R1 = \frac{V(I_{12}) - V(I_{11})}{I_{12} - I_{11}}$$

• Calculation of bias resistor ratio (R2/R1)

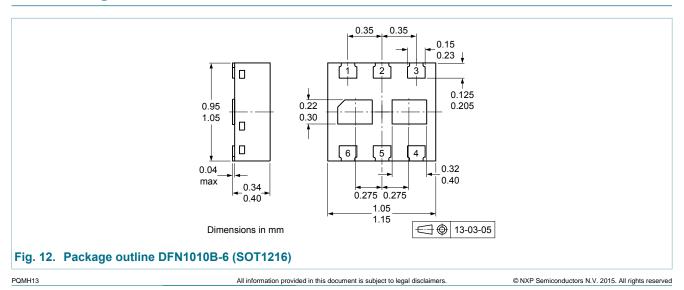
$$\frac{R2}{R1} = \frac{V(I_{14}) - V(I_{13})}{R1 \cdot (I_{14} - I_{13})} - 1$$



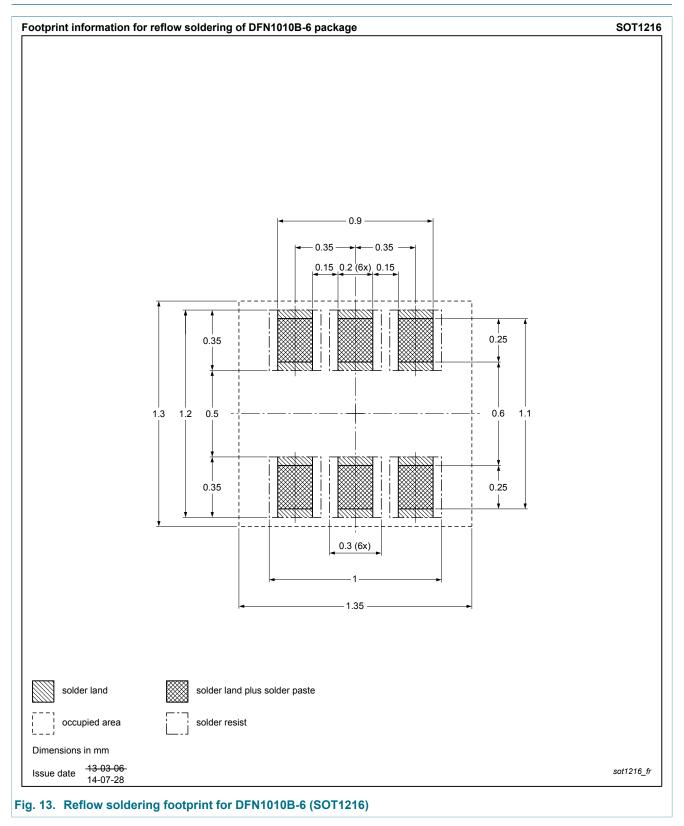
11.3 Resistor test conditions

Table 8.	Resistor test conditions				
R1 (kΩ)	R2 (kΩ)	Test conditions			
		I _{I1}	I ₁₂	I _{I3}	I ₁₄
4.7	47	90 µA	140 µA	-55 μA	-105 μA

12. Package outline



13. Soldering



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14. Revision history

Table 9. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PQMH13 v.1	20151104	Product data sheet	-	-		

15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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